

View Online at <https://aerobasegroup.com/nsn/5961-01-302-7880>

Inclosure Material:

Ceramic

Overall Length:

0.358 inches

Overall Height:

0.100 inches

Overall Width:

0.358 inches

Component Name And Quantity:

2 semiconductor device diode and 2 transistor

Mounting Method:

Press fit

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

15.0 drain to source voltage all transistor

Current Rating Per Characteristic:

100.00 microamperes forward current, dc all semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

All semiconductor device diode junction pattern arrangement: pn

Terminal Type And Quantity:

20 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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